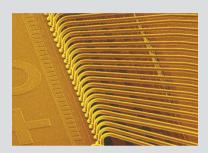
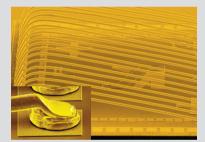
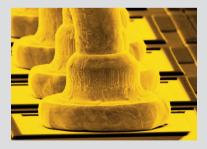
Heraeus

AW-14 Gold Bonding Wire for Universal Use







For the last half decade, AW-14 has been an industry mainstay for applications involving low loops such as those found in TQFP, CSP, TSOP and smart card assembly. Consistent fine grain size and a short heat affected zone allow low heights (as low as $100~\mu m$) and long spans (up to 7 mm). This versatile 4N wire (99.99 % Au) provides very wide parameter window and can be used on virtually all types of equipment for both ball and wedge bonding.

Easy to optimize parameters for a wide range of packages

AW-14 lends itself to a variety of devices (from discretes through TSOPs, QFPs and BGAs for single die, stacked die and die-to-die applications) due to a high modulus and stable properties. AW-14's large process windows provide robust, highly portable bonding in mass production, making it one of the industry's easiest wires to use.

AW-14 Benefits

- Large process window for robust, highly portable mass production
- Proven in the widest range of applications
- Excellent low loop stability and high strength properties for a variety of advanced packaging requirements
- Consistent ball size and fine-grain, short heat affected zone (HAZ) at ball neck
- Easily optimized wire available in diameters down to 17.5 μm (0.7 mil.)
- Compatible with all ball and wedge bonding equipment

AW-14 Low Loop Consistency

All dimensions in microns

Wire	Loop	Std			
Size	Height	Dev	Min.	Max.	n
25	168	4.0	160	168	20
25	150	2.3	146	154	32
33	152	5.8	137	168	100

Bonding Conditions: Wire diameter: 25 µm (1.0 mils) Wire bonder: K&S 1488 turbo · Package type: 208-lead QFP · Die metallization: AlSi (1%) Cu (0.5 %) · Leadframe: Ag-plated Cu · Wire span: 4 – 7 mm · Bonding temperature: 220 °C · Capillary: 414Fa-0310-R35

Recommended Technical Data of AW-14									
Diameter	Microns	18	20	23	25	28	30	32	33
	Mils	0.7	0.8	0.9	1.0	1.1	1.2	1.25	1.3
Recommended Spec for Ball Bonding									
Elongation (%)		2 – 5	2 – 6	2 – 6	2 – 6	2 – 6	2 – 7	2 – 7	2 – 7
Breaking Load (g)		3 – 6	4 – 9	7 – 12	8 - 13	10 - 15	12 - 18	14 – 21	15 - 22
In-Line Pad Pitch (µm)									
Min. In-Line Pad Pitch					65	70	80		

For other diameters, please contact Heraeus Bonding Wires sales representative.

Range of recommended pad pitch with corresponding wire diameter.

AW-14 Characteristics for 25 μm diameter					
Non-Gold Elements	< 100 ppm				
Elastic Modulus	\sim 80 GPa 50 $-$ 190 μ m				
Heat Affected Zone (HAZ)					
Melting Point	1063 °C				
Density	19.32 g/cm ³				
Heat Conductivity	3.17 W/cm·K				
Electrical Resistivity	2.3 μ Ω -cm				
Coeff. of Linear Expansion (20 – 100 °C)	14.2 ppm/K				
Fusing Current for 25 µm, dia 100 mm length (in air)	0.37 A				

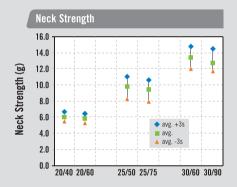
Superior Loop Linearity

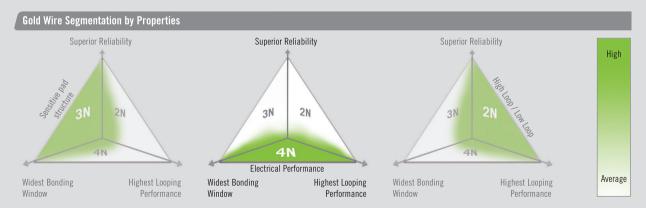
Mold Sweep Resistance

- Auto-Gang Pot Molding
- Sumitomo Compound EME 7320
- Wire diameter 30 µm, wire span up to 7 mm
- Spec. limit 8 % of wire span

DAP					
Size	Span	Avg.	Dev.	Min.	Max.
9 x 9	5 mm	1.2	0.40	0.3	2.1
10.5 x 10.5	6 mm	1.9	0.67	0.8	3.3
12 x 12	7 mm	2.0	0.59	0.8	3.4

Data is in % of wire span, measured at 90 $^{\circ}$ positioned to gate.





Americas Phone +1 610 825 6050

electronics.americas@heraeus.com

Asia Pacific Phone +65 65717649 electronics.apac@heraeus.com

China Phone +86 53 5815 9601 electronics.china@heraeus.com Europe, Middle East and Africa Phone +49 6181 35 4370 electronics.emea@heraeus.com

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